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PATENT NUMBER and
ISSUE DATE

U.S. UTILITY Patent Application

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APPL NUM 10046077	FILING DATE 01/16/2002	CLASS 438	SUBCLASS 270	GAU 2812	EXAMINER
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**APPLICANTS: Inagawa Hiroshi; Machida Nobuo; Oishi Kentaro;
2813

**CONTINUING DATA VERIFIED: *Yes No*

** FOREIGN APPLICATIONS VERIFIED: *Yes*
JAPAN 2001-042352 02/19/2001

PG-PUB <input type="checkbox"/>	DO NOT PUBLISH <input type="checkbox"/>	RESCIND <input type="checkbox"/>
Foreign priority claimed <input checked="" type="checkbox"/> yes <input type="checkbox"/> no	ATTORNEY DOCKET NO. <input checked="" type="checkbox"/>	
35 USC 119 conditions met <input checked="" type="checkbox"/> yes <input type="checkbox"/> no	XA-9612	
Verified and Acknowledged Examiners's initials <i>RA</i>		
TITLE : Insulated gate type semiconductor device and method for fabricating the same		

U.S. DEPT. OF COMM./PAT. & TM.-PTO-436L (Rev. 12-94)

NOTICE OF ALLOWANCE MAILED		CLAIMS ALLOWED	
Assistant Examiner		Total Claims	Print Claim for O.G.
Primary Examiner		DRAWING	
PREPARED FOR ISSUE		Sheets Drwg.	Figs. Drwg.
Application Examiner		Print Fig.	
<input type="checkbox"/> TERMINAL DISCLAIMER		WARNING: The information disclosed herein may be restricted. Unauthorized disclosure may be prohibited by the United States Code Title 35, Sections 122, 181 and 368, Possession outside the U.S. Patent & Trademark Office is restricted to authorized employees and contractors only.	

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